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Electronic structure of the parent compound of superconducting infinite-layer nickelates

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Supplementary Information for Electronic structure in the parent compound of superconducting infinite-layer nickelates

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This Supplementary Information Contains:

Supplementary Table 1-3

Unit eV		Ni [0,0,0]					O[0, ½, 0]			O[½, 0, 0]			La [½,½,½]
		d _{z2}	d _{x2-y2}	d _{xy}	d _{xz}	d _{yz}	p _z	p _x	p _y	p _z	p _x	p _y	d _{z2}
Ni [0,0,0]	d _{z2}	-0.04							-0.3		0.3		-0.5
	d _{x2-y2}		0.70						-1.2		-1.2		
	d _{xy}			-0.1				0.7				0.7	
	d _{xz}				0					-0.8			-0.1
	d _{yz}					0	0.8						0.1
O [0, ½, 0]	p _z					0.8	-2.32	0.2					0.4
	p _x			0.7			0.2	-2.34			0.3	0.2	-0.2
	p _y	-0.3	-1.2						-3.26		0.6	0.3	0.4
O [½, 0, 0]	p _z				-0.8					-2.32		-0.2	0.4
	p _x	0.3	-1.2					0.3	0.6		-3.25		-0.4
	p _y			0.7				0.2	0.3	-0.2		-2.35	0.2
La [½,½,½]	d _{z2}	-0.5			-0.1	0.1	0.4	-0.2	0.4	0.4	-0.4	0.2	2.42

Supplementary Table 1: Material parameters for LaNiO₂ obtained from Wannier downfolding.

The diagonal terms represent on-site energies. The off-diagonal terms represent the hopping between two orbitals. The shaded area only shows those parameters whose absolute value is larger than 0.1. All values are in units of eV. The triplet [i,j,k] appearing next to each orbital shows its

relative position within a one Ni, LaNiO_2 tetragonal unit cell along the unit a, b, and c axes, respectively, with Ni at [0,0,0].

Orbital configuration		Approximate percentage	Dipole transition spin up (minority spin)	Dipole transition spin down (majority spin)
d^9	$d^4 \uparrow d^5 \downarrow$	56%	Yes	No
$d^8 R$	$d^3 R \uparrow d^5 \downarrow$	24%	Yes	No
	$d^4 \uparrow d^4 R \downarrow$	14%	Yes	Yes
$d^7 R^2$	$d^3 R \uparrow d^4 R \downarrow$	6%	Yes	Yes

Supplementary Table 2: Orbital configurations and their approximate percentage shown in the many-body ground state calculation. Here, R represents a rare earth electron in the La cage surrounding each Ni, in analogy to the standard ligand hole (L), due to hybridization between Ni and La. This is akin to charge transfer, but from Ni to the rare earth, instead of oxygen to transition metal more commonly encountered in oxides.

Hopping Parameters from Wannier Downfolding			
i	j	k	$t_{[i,j,k]}^R$
0	0	0	1.132
0	0	1	-0.022
0	0	2	-0.112
0	0	3	0.019
1	0	0	-0.028
1	0	1	-0.164
1	0	2	0.033
1	1	0	-0.062
1	1	1	0.024
1	1	2	0.013
1	1	3	-0.019
2	0	1	0.009
2	1	1	0.009
i	j	k	$t_{[i,j,k]}^{Ni}$
0	0	0	0.267
1	0	0	-0.355
1	1	0	0.090
2	0	0	-0.043
0	0	1	-0.043
1	1	1	0.013
i	j	k	$t_{[i,j,k]}^{R-Ni}$
2	0	0	-0.026
2	0	2	0.013

Supplementary Table 3: Tight-binding model parameters for the two-orbital model for LaNiO₂.

The elements in the table show all independent hopping parameters with an absolute magnitude larger than 0.008 eV. The triplet of integers $[i,j,k]$ represents hopping between unit cells with a relative separation $\mathbf{r} = i \mathbf{a} + j \mathbf{b} + k \mathbf{c}$, where $\mathbf{a}$, $\mathbf{b}$, and $\mathbf{c}$ are unit vectors in the respective directions. Here, for simplicity we take $\mathbf{a}=\mathbf{b}=\mathbf{c}=1$ and measure all momenta k_x , k_y , and k_z , accordingly. Tetragonal symmetry dictates that for the rare earth- (R -) and Ni-band parameters, the hopping with triplet $[i,j,k]$ would be equivalent to $[-i,j,k]$, $[i,-j,k]$, $[i,j,-k]$, $[-i,-j,k]$, $[-i,j,-k]$, $[i,-j,-k]$, $[-i,-j,-k]$, and all combinations with $i \leftrightarrow j$, with a phase factor of 1 or -1 depending on the symmetry of the orbitals. The triplet $[0,0,0]$ represents the orbital site energy ϵ_0 . The La-centered and Ni-centered Wannier orbitals have relative unit cell coordinates $[0.5, 0.5, 0.5]$ and $[0.0, 0.0, 0.0]$, respectively,

which only affects the equivalent triplets for the cross-orbital-hybridization terms t^{R-Ni} . The Fermi energy E_F is at 0 eV.